



FMMT491Q

#### **60V NPN MEDIUM POWER TRANSISTOR IN SOT23**

#### **Description**

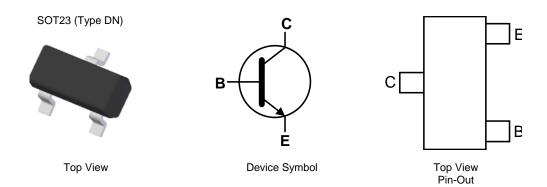
This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of automotive applications.

#### **Feature**

- BV<sub>CEO</sub> > 60V
- I<sub>C</sub> = 1A Continuous Collector Current
- I<sub>CM</sub> = 2A Peak Pulse Current
- $R_{CE(SAT)} = 195m\Omega$  for a Low Equivalent On-Resistance
- 500mW Power Dissipation
- hFE Characterized up to 2A for High Current Gain Hold Up
- Complementary PNP Type: FMMT591Q
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight 0.008 grams (Approximate)



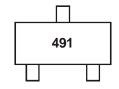
### **Ordering Information** (Note 5)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FMMT491QTA	Automotive	491	7	8	3,000
FMMT491QTC	Automotive	491	13	8	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**



491 = Product Type Marking Code



# Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	80	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ic	1	Α
Peak Pulse Current	I <sub>CM</sub>	2	Α
Base Current	I <sub>B</sub>	200	mA

# Thermal Characteristics ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P <sub>D</sub>	500	mW
Thermal Resistance, Junction to Ambient (Note 6)	R <sub>0JA</sub>	250	°C/W
Thermal Resistance, Junction to Lead (Note 7)	$R_{ heta JL}$	197	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

## ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

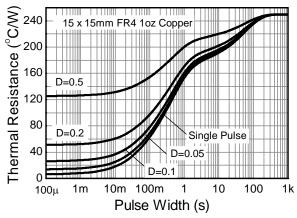
<sup>6.</sup> For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.

7. Thermal resistance from junction to solder-point (at the end of the collector lead).

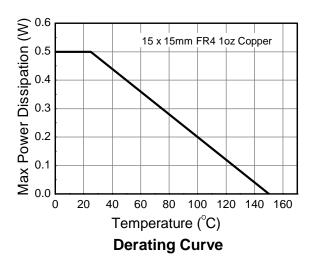
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

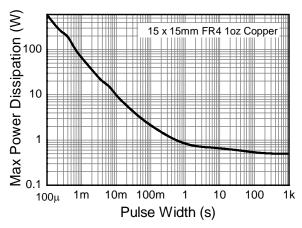


### **Thermal Characteristics and Derating Information**



**Transient Thermal Impedance** 





**Pulse Power Dissipation** 



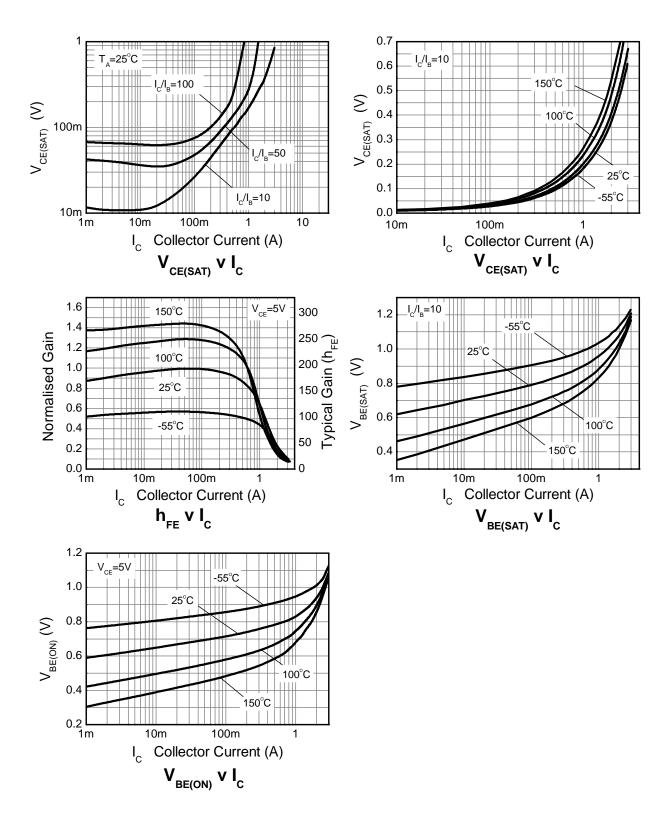
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	80	_	_	V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	60	_	_	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.1	_	V	$I_E = 100\mu A$
Collector Cutoff Current	I <sub>CBO</sub>	_	<1	100	nA	V <sub>CB</sub> = 60V
Emitter Cutoff Current	I <sub>EBO</sub>	_	<1	100	nA	V <sub>EB</sub> = 5.6V
Collector Emitter Cutoff Current	I <sub>CES</sub>	_	<1	100	nA	V <sub>CE</sub> = 60V, V <sub>CES</sub> = 60V
		100	140	_	_	$I_C = 1mA$ , $V_{CE} = 5V$
Chatia Famusard Comment Transfer Datia (Nata O)	h <sub>FE</sub>	100	150	300		$I_C = 500 \text{mA}, V_{CE} = 5 \text{V}$
Static Forward Current Transfer Ratio (Note 9)		80	120	_		$I_C = 1A, V_{CE} = 5V$
		30	40	_		$I_C = 2A, V_{CE} = 5V$
Collector Emitter Seturation Voltage (Note 0)	V <sub>CE(SAT)</sub>	_	100	150	\/	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$
Collector-Emitter Saturation Voltage (Note 9)		_	160	250	mV	I <sub>C</sub> = 1A, I <sub>B</sub> = 100mA
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(ON)</sub>	_	830	1,000	mV	$I_{C} = 1A, V_{CE} = 5V$
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(SAT)</sub>	_	965	1,100	mV	I <sub>C</sub> = 1A, I <sub>B</sub> = 100mA
Output Capacitance	C <sub>OBO</sub>	_	_	10	pF	V <sub>CB</sub> = 10V, f = 1MHz
Transition Frequency	f <sub>T</sub>	150	_	_	MHz	V <sub>CE</sub> = 10V, I <sub>C</sub> = 50mA, f = 100MHz

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



### Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

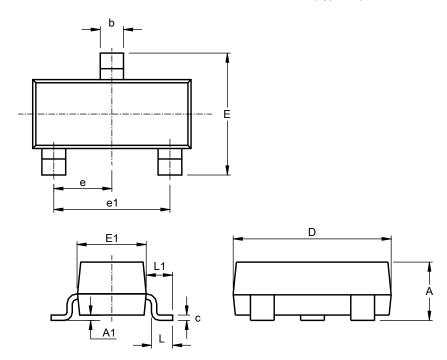




### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23 (Type DN)

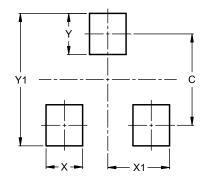


SOT23 (Type DN)					
Dim	Min	Max	Тур		
Α	0.89	1.12	1.00		
A1	0.01	0.10	0.05		
b	0.30	0.51	0.45		
С	0.08	0.20	0.10		
D	2.80	3.04	3.00		
Е	2.10	2.64	2.42		
E1	1.20	1.40	1.37		
е	0.95 REF				
e1	1.90 REF				
٦	0.25	0.60	0.30		
L1	0.45	0.62	0.54		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23 (Type DN)



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Υ	0.9
V1	2.0



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